MGBR20L60 Preliminary DIODE

# MOS GATED BARRIER RECTIFIER

### **■** DESCRIPTION

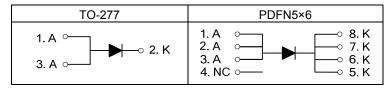
The UTC MGBR20L60 is a surface mount mos gatedbarrier rectifier, it uses UTC's advanced technology to provide customers withlow forward voltage drop and high switching speed, etc.

### **■ FEATURES**

- \* Low forward voltage drop
- \* High switching speed

# 1 PDFN5×6 1 TO-277

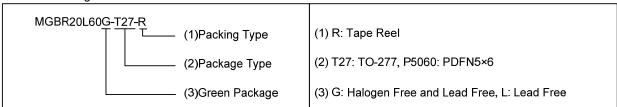
### ■ SYMBOL



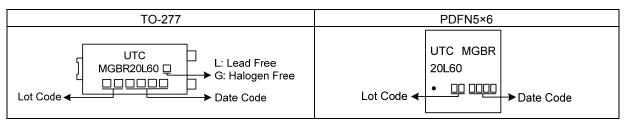
### ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment							Dealing		
Lead Free	Halogen Free	Package	1	2	3	4	5	6	7	8	Packing	
MGBR20L60L-T27-R	MGBR20L60G-T27-R	TO-277	Α	K	Α	-	1	-	-	-	Tape Reel	
MGBR20L60L-P5060-R	MGBR20L60G-P5060-R	PDFN5×6	Α	Α	Α	NC	Κ	Κ	Κ	Κ	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



### **■ MARKING**



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# ■ **ABSOLUTE MAXIMUM RATINGS**(T<sub>A</sub>=25°C, unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage	$V_{RM}$	60	V
WorkingPeak Reverse Voltage	$V_{RWM}$	60	V
Peak Repetitive Reverse Voltage	$V_{RRM}$	60	V
Average Rectified Output Current T <sub>C</sub> =140°C	Io	20	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	250	Α
Repetitive Peak Avalanche Power (1µs, 25°C)	P <sub>ARM</sub>	5000	W
Operating Junction Temperature	TJ	-65 ~ <b>+</b> 150	°C
Storage Temperature	T <sub>STG</sub>	-65 ~ <b>+</b> 150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

## **■ THERMAL DATA (Note)**

PARAMETE	ER	SYMBOL	RATINGS	UNIT
lumation to Ambient	TO-277	0	73	°C/W
Junction to Ambient	PDFN5×6	$\theta_{JA}$	73 72 13	°C/W
lunation to Occa	TO-277	$\theta_{ m JC}$	13	°C/W
Junction to Case	PDFN5×6		3.4	°C/W

Note: Mounted on an FR4 PCB, single-sided copper, with 100 cm<sup>2</sup> copper pad area.

# ■ **ELECTRICAL CHARACTERISTICS**(T<sub>A</sub>=25°C,unless otherwise specified.)

PARAMETER	PARAMETER SYMBOL TEST CONDITIONS		MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I <sub>R</sub> =0.5mA	60			V
Forward Voltage Drop		I <sub>F</sub> =20A, T <sub>J</sub> =25°C			0.65	٧
	$V_{FM}$	I <sub>F</sub> =20A, T <sub>J</sub> =125°C			0.60	V
Laglage Comment (Nata 1)		V <sub>R</sub> =60V, T <sub>J</sub> =25°C		85	300	μΑ
Leakage Current (Note 1)	IRM	V <sub>R</sub> =60V, T <sub>J</sub> =125°C		12	40	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

<sup>2.</sup> Thermal resistance junction to case mounted on heatsink.

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